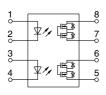


# Normally closed type with reinforced insulation

### PhotoMOS® GE 2 Form B (AQW414EH)

#### 9.86 3.388 3.2 1.126 9.86 2.52 2.388 2.52 1.114 (Height includes standoff)

mm inch



**RoHS** compliant

### **FEATURES**

- 1. Reinforced insulation of 5,000 V More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).
- 2. Applicable for 2 Form B use as well as two independent 1 Form B use
- **3. Controls low-level analog signals**PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 4. High sensitivity and high speed response

Can control max. 0.13 A load current with 5 mA input current. Fast operation speed of Typ. 0.8 ms.

5. Low-level off state leakage current

### TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Electricity, plant equipment
- Security equipment
- Sensing equipment

### **TYPES**

	I/O isolation voltage	Output rating*		Dooksons	Part No.				Packing quantity	
					Through hole terminal Surface-mount terminal					
		Lood	ad Load	Package		Tape and reel p		packing style	cking style	
		Load voltage			Tube packing style		Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Tube	Tape and reel
AC/DC dual use	Reinforced 5,000 Vrms	400 V	100 mA	DIP8-pin	AQW414EH	AQW414EHA	AQW414EHAX	AQW414EHAZ	1 tube contains : 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

<sup>\*</sup>Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

### **RATING**

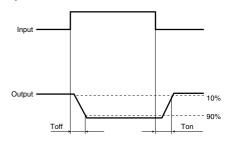
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW414EH(A)	Remarks		
Input	LED forward current	lF	50mA			
	LED reverse voltage	VR	5V			
	Peak forward current	IFP	1A	f =100 Hz, Duty factor = 0.1%		
	Power dissipation	Pin	75mW			
Output	Load voltage (peak AC	) V <sub>L</sub>	400 V			
	Continuous load currer	nt IL	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1 channel.		
	Peak load current	Ipeak	0.3 A	100 ms (1 shot), V <sub>L</sub> = DC		
	Power dissipation	Pout	800mW			
Total power dissipation		P⊤	850mW			
I/O isolation voltage		Viso	5,000 Vrms			
Ambient	Operating	Topr	<b>−40 to +85°C</b> −40 to +185°F	(Non-icing at low temperatures)		
temperat	ture Storage	T <sub>stg</sub>	-40 to +100°C -40 to +212°F			

### 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item		Symbol AQW414EH(A)		Condition	
Input	LED operate (OFF) current	Typical	- <b>I</b> Foff	1.3mA	IL=Max.	
	LED operate (OFF) current	Maximum	IF-off	3.0mA	IL=IVIAX.	
	LED reverse (ON) current	Minimum	- IFon	0.4mA	IL=Max.	
	LED reverse (ON) current	Typical	IFon	1.2mA	IL=IVIAX.	
	LED dropout voltage	Typical	VF	1.25 (1.14 V at I⊧=5mA)	I <sub>F</sub> =50mA	
	LED dropout voltage	Maximum	VF	1.5V	IF=50IIIA	
Output		Typical		26Ω	I <sub>F</sub> =0mA	
	On resistance	Maximum	Ron	35Ω	I∟=Max. Within 1 s	
	Off state leakage current	Maximum	ILeak	10μΑ	I <sub>F</sub> =5mA V <sub>L</sub> =Max.	
	Operate (OFF) time*	Typical	- T <sub>off</sub>	0.8ms	I⊧=0mA→5mA	
	Operate (OFF) time	Maximum	I off	3.0ms	I∟=Max.	
	Reverse (ON) time*	Typical	- T <sub>on</sub>	0.2ms	I⊧=5mA→0mA	
Transfer characteristics	neverse (ON) time	Maximum	Ion	1.0ms	I∟=Max.	
	I/O sanasitanas	Typical		0.8pF	f =1MHz	
	I/O capacitance	Maximum	Ciso	1.5pF	V <sub>B</sub> =0V	
	Initial I/O isolation resistance	Minimum	Riso	1,000ΜΩ	500V DC	

### \*Operate/Reverse time



### 3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

	Item	Symbol	Number of used channels	Min.	Max.	Unit
LED current		lF		5	30	mA
	Load voltage (Peak AC)	V∟		_	320	V
AQW414EH(A)	Continuous load current	lL	1ch 2ch	_	0.13 0.1	А

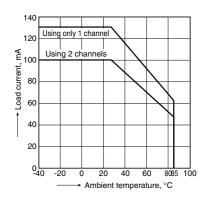
### ■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

### REFERENCE DATA

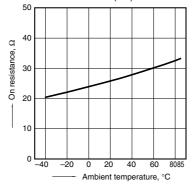
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C



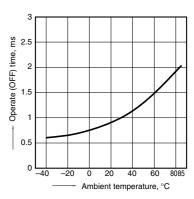
## 2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 0 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



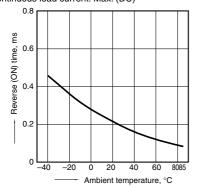
# 3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



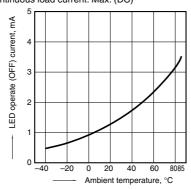
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



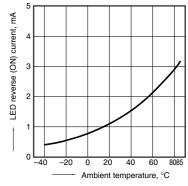
5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: Max. (DC);

Continuous load current: Max. (DC)

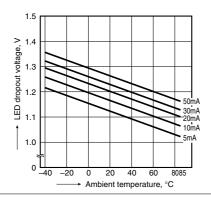


### 6. LED reverse (ON) current vs. ambient temperature characteristics Load voltage: Max. (DC);

Continuous load current: Max. (DC)

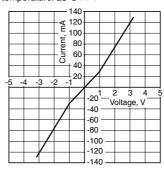


#### 7. LED dropout voltage vs. ambient temperature characteristics; LED current: 5 to 50 mA



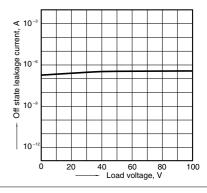
### 8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 7



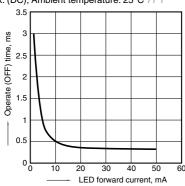
### 9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



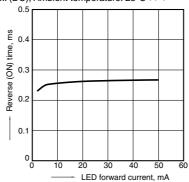
### 10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77



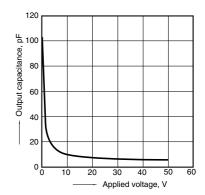
### 11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77



### 12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



"PhotoMOS", "PhotoMOS" and "PHOTOMOS" are registered trademarks of Panasonic Corporation.
\*Recognized in Japan, the United States, all member states of European Union and other countries.

Please contact .....

# Panasonic Corporation Electromechanical Control Business Division

■ 1006, Oaza Kadoma, Kadoma-shi, Osaka 571-8506, Japan industrial.panasonic.com/ac/e/



©Panasonic Corporation 2017

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

### Panasonic:

AQW414EH AQW414EHA AQW414EHAZ AQW414EHAZ